



Failed

Saved

- ↳ S1: (119) "6545906"
- ↳ S5: (2) "20020163058"
- ↳ S4: (1) 10/261225
- ↳ S3: (1) 11/240179
- ↳ S2: (29) "6567246"
- ↳ S6: (26) "6117747"
- ↳ S7: (1) 11/155340
- ↳ S8: (1722) plasma near reaction near chamber
- ↳ S9: (12) RF near plasma near reaction near chamber
- ↳ S10: (188) S8 same reactor
- ↳ S11: (2) 10/715376

Buttons: Search, Advanced, Browse, Delete, Clear

DBs: US-PPRUB; USPAT; EPO; IPO; DERWENT; IBM_TDB

Default operator: OR

 Exact
 Highlight all hit terms initially

10/715376

BRS form ISTR form Images Text HTML

U	Document ID	Issue Date	Pages	Title	Current OR	Current XRef	Retrieval Cls	Inventor	S	C	P	3	Image	Doc.	Display	PT
1	<input type="checkbox"/> US 20060104110	20060518	15	Spin-current switchable magnetic memory element and method of fabrication	365/173			Sun, A1	<input checked="" type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20060104110		<input type="checkbox"/>
2	<input type="checkbox"/> US 20050104101	20050519	14	Spin-current switched magnetic memory element suitable for circuit integration	257/295	257/E27.005;		Sun, A1	<input checked="" type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	US 20050104101		<input type="checkbox"/>

Has: Delete HTML

[NUM]

Ready